Features



Ultra3 LVD/SE SCSI 14-Line Terminator

General Description

The DS2127 Ultra3 LVD/SE SCSI terminator provides low-voltage differential (LVD)/single-ended (SE) terminations for 14 SCSI lines. Through the voltage on the DIFF_CAP pin, the device detects the types of drivers on the bus. If the device is connected in an LVD-only bus, the DS2127 provides LVD termination. If any single-ended devices are connected to the bus, the DS2127 uses SE termination. If any high-voltage differential (HVD) devices are connected to the bus, the DS2127 isolates itself from the SCSI bus. The mode change has a built-in delay that is determined by an integrated SPI-3 mode change filter/delay. The terminating resistors can also be disconnected from the bus by asserting the ISO pin.

For the LVD termination, the DS2127 provides 14 precisely trimmed resistors. Each resistor is biased with two current sources to a fail-safe state. For SE termination, the DS2127 provides 14 precision 110Ω resistors and one regulator for active-negation bias.

Applications

SCSI Array Backplane SCSI Cables

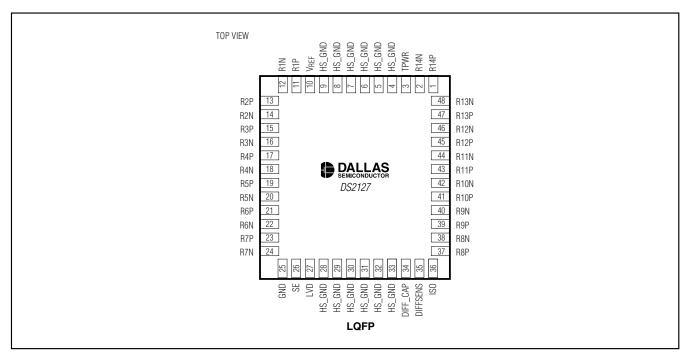
♦ Fully Compliant with Ultra2, Ultra3, Ultra160, and

- **Ultra320 SCSI Standards** ♦ Provides LVD/SE Termination for 14 Signal Pairs
- **♦** Auto-Selection of LVD or SE Termination
- ♦ 5% Tolerance on SE and LVD Termination Resistance
- **♦ Low 3pF Power-Down Capacitance**
- ♦ Built-In Mode-Change Filter/Delay
- ♦ On-Board Thermal-Shutdown Circuitry
- ♦ SCSI Bus Hot-Plug Compatible
- **♦ Fully Supports Actively Negated SE SCSI Signals**

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
DS2127	0°C to +70°C	48 LQFP	DS2127

Pin Configuration



ABSOLUTE MAXIMUM RATINGS

Voltage Range on All Pins Relative to Groun	d0.3V to +6.0V
VREF Continuous Output Current	±200mA
Operating Temperature Range	
Junction Temperature	+150°C

Storage Temperature Range	65°C to +160°C
Soldering Temperature	See IPC/JEDEC
	J-STD-020A Specification

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(TPWR = V_{TPWR}(MIN) to V_{TPWR}(MAX), T_A = 0°C to +70°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
TPWR Operating Supply Range (Note 1)	VTPWR	LVD	2.7	3.3	5.5	V	
		SE	4	5.0	5.5] V	
TPWR SUPPLY CURRENT							
TDIA/D Company (All Lines	ITPWR_LVD	LVD SCSI mode			32	mA	
TPWR Supply Current (All Lines Open)	ITPWR_SE	SE SCSI mode			10	1117 \	
Орону	ITPWR_ISO	ISO mode (terminators disabled)			750	μΑ	
LVD TERMINATION (Applies to ea	LVD TERMINATION (Applies to each line pair, 1 to 14 in LVD mode)						
Differential-Mode Termination Resistance	R _{DM}		100		110	Ω	
Common-Mode Termination Resistance	R _{CM}	R_P and R_N shorted together $(V_{CM(MAX)} = 2V, V_{CM(MIN)} = 0.5V)$	110		165	Ω	
Differential-Mode Bias	V_{DM}	All lines open	100		125	mV	
Common-Mode Bias	V _{CM}	R _P and R _N shorted together (Note 1)	1.15	1.25	1.35	V	
SE TERMINATION (Applies to sing	gle-ended ter	rminators, 1 to 14 in SE mode)					
Single-Ended Mode Termination Resistance	R _{SE}	$\begin{split} R_{SE} &= \left(V_{LX} - 0.2\right) / I_{LX}, \text{ where } V_{LX} = \text{voltage} \\ \text{at terminator pin with pin unloaded and} \\ I_{LX} &= \text{current for each terminator pin with} \\ \text{the pin forced to } 0.2V \end{split}$	104.5	110	115.5	Ω	
T	I _{SE}	Signal level at 0.2V, all lines low	-21	-24	-25.4	mA	
Termination Current		Signal level at 0.5V	-18		-22.4		
SE Voltage Reference	V _{REF}		2.7	2.85	3.0	V	
Pin Leakage		With ISO high			400	nA	
Single-Ended GND Resistance	RGND	Measured at Rp pins, I = 10mA		20	60	Ω	
TERMINATOR PIN CAPACITANC	TERMINATOR PIN CAPACITANCE						
Terminator Pin Capacitance	CIN	With ISO high (Note 2)			3	рF	
V _{REF} REGULATOR							
1.25V Regulator Output Voltage	V _{REF_LVD}	$0.5V \le V_{CM} \le 2.0V$, V_{CM} applied to all R _P and R _N lines simultaneously	1.15	1.25	1.35	V	
1.25V Regulator Short-Circuit Source Current	ISOURCE	V _{REF} = 0V	-375	-700	-1000	mA	
1.25V Regulator Short-Circuit Sink Current	ISINK	V _{REF} = 3.3V	170	300	700	mA	

ELECTRICAL CHARACTERISTICS (continued)

(TPWR = V_{TPWR(MIN)} to V_{TPWR(MAX)}, T_A = 0°C to +70°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
V _{REF} REGULATOR						
1.25V Regulator Line Regulation		V _{REF} unloaded; vary TPWR from 2.7V to 5.5V		1.0	2.5	%
2.85V Regulator			2.7	2.85	3.0	V
2.85V Regulator Short-Circuit Source Current		V _{REF} = 0V	-375	-700	-1000	mA
2.85V Regulator Short-Circuit Sink Current		V _{REF} = 3.3V	170	300	700	mA
2.85V Regulator Line Regulation		V _{REF} unloaded; vary TPWR from 2.7V to 5.5V		1.0	2.5	%
DIFFSENS OUTPUT	•		1			
DIFFSENS Driver Output Voltage	V _{DSO}	-5mA ≤ IDIFFSENS ≤ 50μA	1.2		1.4	V
DIFFSENS Driver Source Current	IDSH	VDIFFSENS = 0V	-15		-5	mA
DIFFSENS Driver Sink Current	I _{DSL}	V _{DIFFSENS} = 2.75V	100		200	μΑ
DIFFSENS Leakage (Note 3)	ILEAK, LOW	With ISO high, IVDIFFSENSI = 0.3V	-3		+1	μΑ
	I _{LEAK} , HIGH	With ISO high, IVDIFFSENS - VTPWRI = 0.3V	1		3	
THERMAL SHUTDOWN			1			
Thermal-Shutdown Threshold		For increasing temperature		130		°C
Thermal-Shutdown Hysteresis				10		ô
MODE CHANGE DELAY/FILTER						
Mode Change Delay	tDELAY		0.66	1.25	2.00	ms
LOGICAL SIGNALS (ISO)						
Input Low Voltage	VIL		-0.3		+0.8	V
Input High Voltage	V _{IH}		2.0	TPW	/R + 0.3	V
Input Current	I _Ι L	V _{CC} = 3.3V	-30	-10		μΑ
STATUS BITS (LVD, SE)						
Source Current	Іон	$V_{CC} = 3.3V$, $V_{LOAD} = 2.4V$	-4	-6		mA
Sink Current	loL	$V_{CC} = 3.3V$, $V_{LOAD} = 0.4V$	2	5		mA
DIFF_CAP						
Input Current	IL	V _{IL} = -0.3V	-1		+1	μΑ
DIFF_CAP SE Operating Range	VSEOR		-0.3		+0.5	V
DIFF_CAP LVD Operating Range	V _L VDOR		0.7		1.9	V
DIFF_CAP HVD Operating Range	V _{HVDOR}		2.4	V _{TP} \	_{VR} + 0.3	V

Note 1: All voltages are referenced to ground.

Note 2: Guaranteed by design and not production tested.

Note 3: Room temperature only.



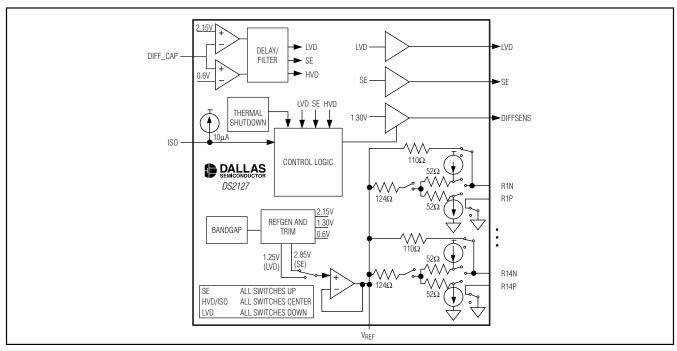


Figure 1. Block Diagram

Pin Description

PIN	NAME	FUNCTION		
1, 2, 11–24, 37–48	RP, RN	Signal Termination. Connect to SCSI bus signal lines. Asserting ISO removes the terminators from the SCSI bus. R_P pins are the ground line for SE operation and the positive lines in differential mode. R_N pins are the signal lines in SE operation and the negative lines in differential mode.		
3	TPWR	Termination Power. Connect to the SCSI TERMPWR line and decouple with a ceramic 2.2µF capacitor.		
4–9, 28–33	HS_GND	Heat-Sink Ground. Internally connected to the mounting pad. These pins must be connected to ground. These pins should be connected to a ground plane with the layout optimized for heat transfer.		
10	V _{REF}	Regulator Output Voltage. This must be decoupled with a 4.7µF capacitor. Asserting ISO floats this output. A high-frequency capacitor (0.1µF) should also be placed on the V _{REF} pin in applications that use fast rise/fall-time drivers.		
25	GND	Signal Ground		
26	SE SE Mode Indicator. A high state indicates SE mode detected on SCSI bus.			
27	LVD Mode Indicator. A high state indicates LVD mode detected on SCSI.			
DIFF_CAP DIFFSENSE Capacitor. Connect a 0.1μF capacitor for the DIFFSENSE filter. Input device (differential or single-ended) on the SCSI bus.		DIFFSENSE Capacitor. Connect a 0.1µF capacitor for the DIFFSENSE filter. Input to detect the type of device (differential or single-ended) on the SCSI bus.		
35	DIFFSENS	DIFFSENSE. Output to drive the SCSI bus DIFFSENS line.		
36	ISO	Isolation Input. When pulled high, terminating resistors and biasing current sources are removed from the SCSI bus. When not connected to ground, the pin has a 10µA current source pulling the pin to the high state.		

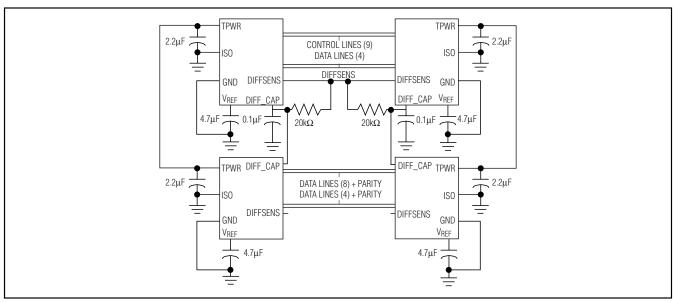


Figure 2. Typical Operating Circuit

Detailed Description

The DS2127 provides dual-mode active terminators with auto-switching SE and LVD termination for 14 SCSI lines. The DIFFSENSE signal performs mode detection and selection.

In LVD mode, the termination configuration is a y-type terminator with a 105Ω differential resistance and a 150Ω common-mode resistance. The termination resistor is biased with two current sources and the common-mode node is connected to a 1.25V voltage regulator. A fail-safe bias of 112mV is maintained when no drivers are connected to the SCSI bus.

In SE mode, each negative signal input pin is connected to 2.85V through a 110Ω resistor.

In HVD mode, the termination resistors are isolated from the SCSI bus and the resistor pins are left floating. The voltage regulator is powered down and the V_{REF} pin is in a high-impedance state.

The DIFF_CAP pin is connected to the SCSI DIFFSENSE line and monitors the voltage to determine the proper operating mode of the device. Any DIFFSENSE voltage below 0.5V indicates single ended; any DIFFSENSE voltage between 0.7V and 1.9V is LVD, and above 2.4V is an HVD SCSI. On power-up, the DS2127 assumes SE mode. If the voltage on the DIFF_CAP is between 0.7V and 1.9V, the device waits tDELAY before entering the LVD mode. The delay is the same when changing modes. A new mode change can start at any time after a previous mode change has been detected.

Typically, four DS2127s are used in a SCSI bus segment. On two chips, the DIFF_CAP inputs at each end of the bus should be connected together. There should be a 50Hz noise filter implemented on DIFF_CAP at each end of the bus, as close as possible to the DIFF_CAP pins. This filter consists of a $20k\Omega$ resistor between the DIFFSENS and DIFF_CAP pins, and a $0.1\mu F$ capacitor from DIFF_CAP to GND. See Figure 2 for the typical operating circuit.

When ISO is connected to TPWR, the termination pins are isolated from the SCSI bus and V_{REF} becomes inactive, and the device is in a low-power state. During thermal shutdown, the termination pins are isolated from the SCSI bus and V_{REF} becomes high impedance. The DIFFSENS driver is shut down during either of these two events. LVD and SE signals indicate whether the SCSI bus segment is in LVD or SE mode.

Chip Information

TRANSISTOR COUNT: 8114 CMOS and 87 Bipolar

PROCESS: BICMOS

SUBSTRATE CONNECTED TO GROUND

Thermal Information

Thermal Resistance (junction-to-ambient): $\theta_{JA} = +29$ °C/W

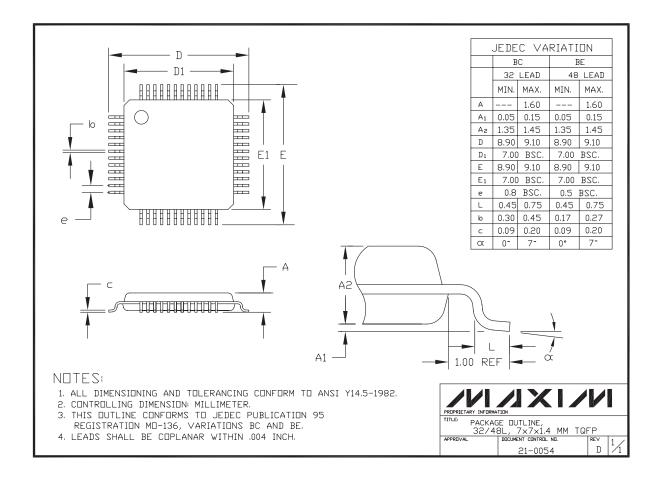
Thermal Resistance (junction-to-case):

 $\theta_{JC} = +10^{\circ}C/W$



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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